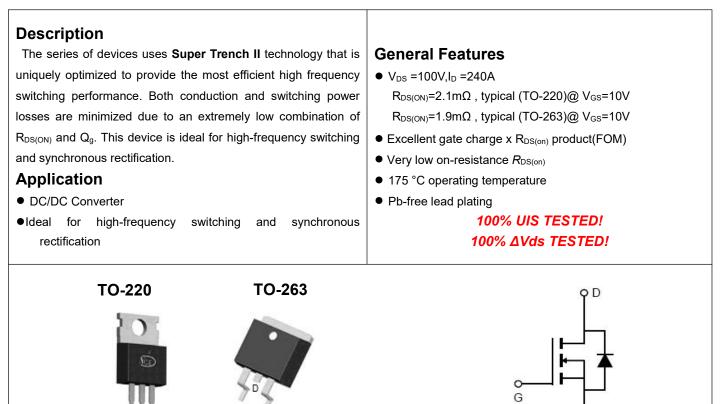


NCE N-Channel Super Trench II Power MOSFET



Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP023N10	NCEP023N10	TO-220	-	-	-
NCEP023N10D	NCEP023N10D	TO-263	-	-	-

Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	240	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	170	A
Pulsed Drain Current	I _{DM}	960	A
Maximum Power Dissipation	PD	340	W
Derating factor		2.27	W/℃
Single pulse avalanche energy (Note 4)	E _{AS}	2332	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	°C



Thermal Characteristic

Thermal Resistance, Junction-to-Case	R _{θJC}	0.44	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	R _{0JA}	60	°C/W

Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition		Min	Тур	Мах	Unit
Off Characteristics				·			•
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA		100		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _G	s=0V	-	-	1	μA
Gate-Body Leakage Current	Igss	V _{GS} =±20V,V _{DS} =0V		-	-	±100	nA
On Characteristics (Note 2)				•			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =2	50µA	2.0	3.0	4.0	V
Desire Oscillator Oscillator Desiretoria			TO-220	-	2.1	2.3	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =120A	TO-263		1.9	2.3	mΩ
Gate resistance	R _G			-	2.9	-	Ω
Forward Transconductance	g fs	V _{DS} =5V,I _D =120A			200	-	S
Dynamic Characteristics (Note3)							
Input Capacitance	C _{lss}	- V _{DS} =50V,V _{GS} =0V, - F=1.0MHz		-	17000	-	PF
Output Capacitance	Coss			-	1500	-	PF
Reverse Transfer Capacitance	Crss			-	77	-	PF
Switching Characteristics (Note 3)							
Turn-on Delay Time	t _{d(on)}			-	37	-	nS
Turn-on Rise Time	tr	V _{DD} =50V,I _D = ⁻	120A	-	29	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =10V,R _G =	1.6Ω	-	82	-	nS
Turn-Off Fall Time	t _f			-	34	-	nS
Total Gate Charge	Qg		004	-	252	-	nC
Gate-Source Charge	Qgs	- V _{DS} =50V,I _D =120A, - V _{GS} =10V		-	72		nC
Gate-Drain Charge	Q _{gd}			-	63		nC
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	Vsd	V _{GS} =0V,I _S =120A		-		1.2	V
Diode Forward Current (Note 2)	Is			-	-	240	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, I⊧ =	120A	-	105	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note2)		-	290	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

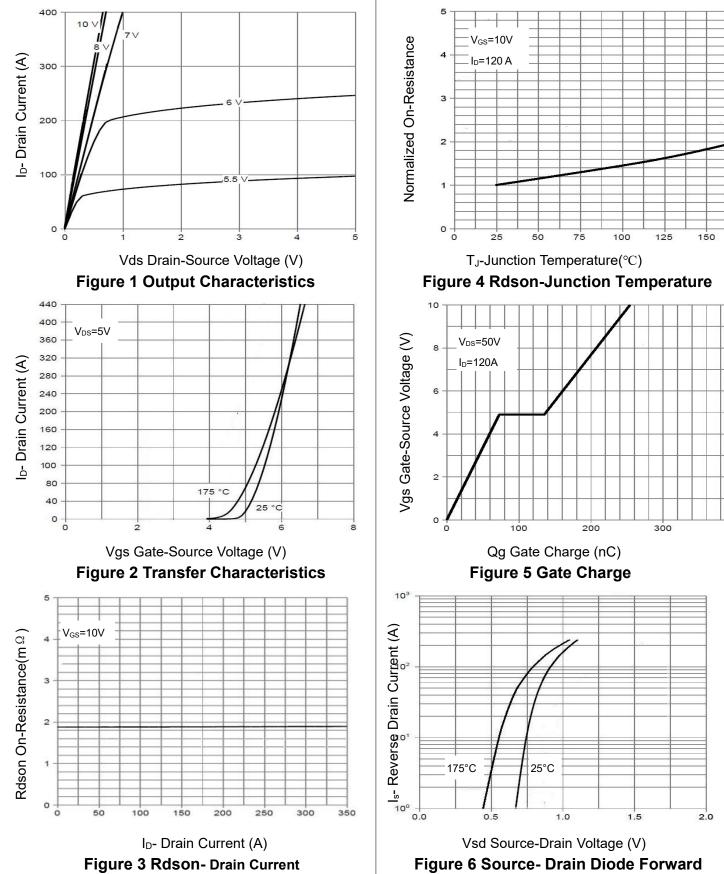
2. The value of R_{0JA} is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^{\circ}$ C. The Power dissipation P_{DSM} is based on R _{0JA} and the maximum allowed junction temperature of 150° C. The value in any given application depends on the user's specific board design, and the maximum temperature of 175° C may be used if the PCB allows it.

3. Guaranteed by design, not subject to production

4. EAS condition : Tj=25 $^\circ\!\!\mathrm{C},V_{DD}$ =50V,V_G=10V,L=0.5mH,Rg=25 Ω



Typical Electrical and Thermal Characteristics

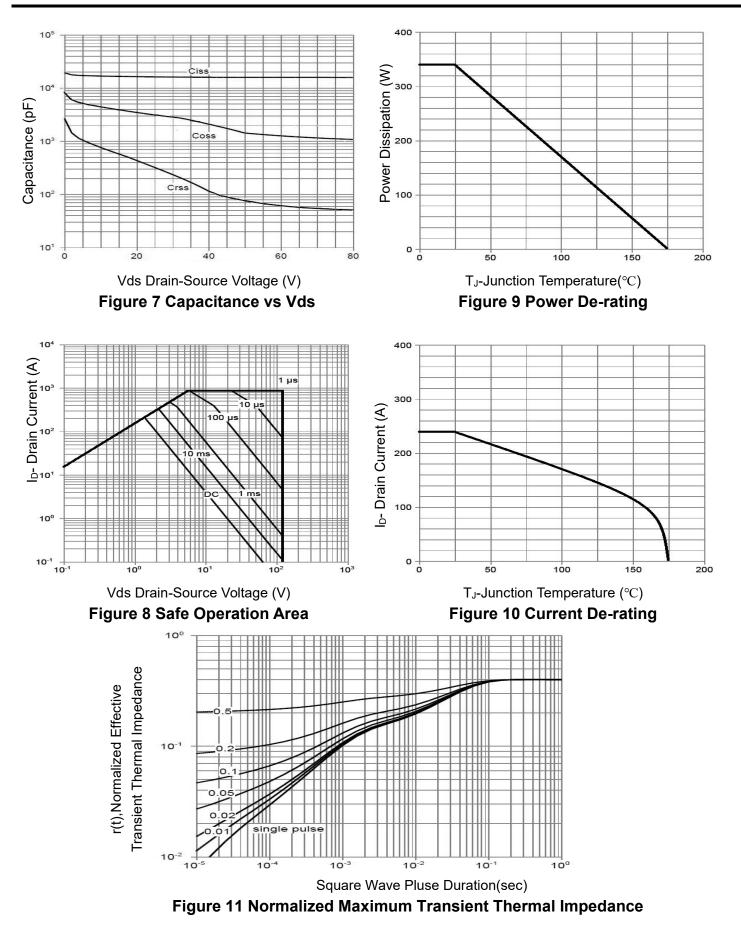


175

400

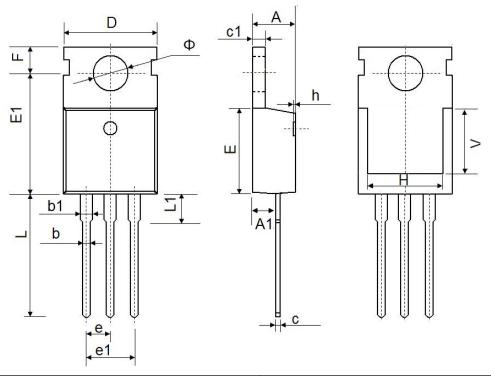


NCEP023N10, NCEP023N10D





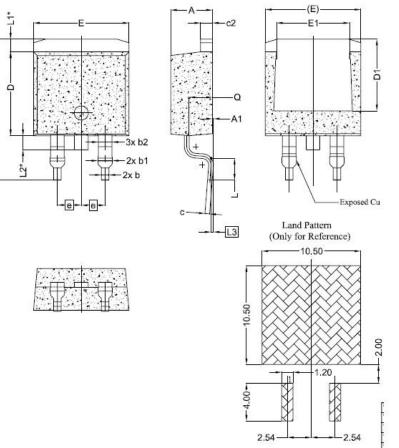
TO-220-3L Package Information



Cumhal	Dimensions	In Millimeters	Dimension	s In Inches
Symbol	Min.	Max.	Min.	Max.
A	4.400	4.600	0.173	0.181
A1	2.250	2.550	0.089	0.100
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
с	0.330	0.650	0.013	0.026
c1	1.200	1.400	0.047	0.055
D	9.910	10.250	0.390	0.404
E	8.9500	9.750	0.352	0.384
E1	12.650	12.950	0.498	0.510
е	2.540	TYP.	0.100	TYP.
e1	4.980	5.180	0.196	0.204
F	2.650	2.950	0.104	0.116
Н	7.900	8.100	0.311	0.319
h	0.000	0.300	0.000	0.012
L	12.900	13.400	0.508	0.528
L1	2.850	3.250	0.112	0.128
V	6.900	6.900 REF. 0.276 REF.		REF.
Φ	3.400	3.800	0.134	0.150



TO-263-2L Package Information



SYMBOL	DIMENSIONS				
SYMBOL	MIN,	NOM.	MAX.		
А	4.24	4.44	4.64		
A1	0.00	0.10	0.25		
b	0,70	0.80	0.90		
b1	1.20	1,55	1,75		
b2	1,20	1,45	1,70		
с	0.40	0.50	0.60		
c2	1,15	1,27	1,40		
D	8.82	8.92	9.02		
D1	6.86	7.65			
E	9,96	10,16	10,36		
E1	6.89	7,77	7,89		
е	2.54 BSC				
н	14,61	15,00	15,88		
L	1.78	2.32	2.79		
L1	1.36 REF.				
L2	1.50 REF.				
L3	0.25 BSC				
Q	2,30	2,48	2.70		



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